Diode Semiconductor Device - Page 1 of 1



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#### Inclosure Material:

Metal

**Overall Length:** 

1.656 inches

# Mounting Facility Quantity:

1

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do5

## **Mounting Method:**

Threaded stud

#### **Features Provided:**

Electrostatic sensitive and hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.667 inches and 0.687 inches

#### Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

35.0 working peak reverse voltage and 35.0 reverse voltage, instantaneous

## **Current Rating Per Characteristic:**

75.00 amperes forward current, average

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

## **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

1 threaded stud and 1 uninsulated wire lead w/terminal lug

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

## Fiig:

A110a0